Product data sheet

#### **Product profile** 1.

## 1.1 General description

Enhanced ultrafast power diode in a SOT428 (DPAK) surface-mountable plastic package.

#### 1.2 Features and benefits

- High thermal cycling performance
- Low on-state losses
- Low thermal resistance

- Soft recovery characteristic
- Surface-mountable package

## 1.3 Applications

- Dual mode (DCM and CCM) Power Factor Correction (PFC)
- Power Factor Correction (PFC) for Interleaved Topology
- U-inverter (DC-AC converter for individual solar panels)

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	-	600	V
I <sub>F(AV)</sub>	average forward current	square-wave pulse; $\delta$ = 0.5; $T_{mb} \le$ 115 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	9	Α
Static char	racteristics					
V <sub>F</sub>	forward voltage	$I_F = 8 \text{ A}; T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 5}}{}$	-	1.45	1.9	V
		$I_F = 8 \text{ A}; T_j = 150 \text{ °C}; \text{ see } \frac{\text{Figure 5}}{}$	-	1.25	1.7	V
Dynamic o	haracteristics					
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V};$ $dI_F/dt = 100 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C};$ see Figure 6	-	17.5	35	ns



# 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		w 14 ·
2	K	cathode[1]	mb	K — A 001aaa020
3	Α	anode		
mb	K	mounting base; connected to cathode	1 3	
			SOT428 (DPAK)	

<sup>[1]</sup> It is not possible to connect to pin 2 of the SOT428 package.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYV29FD-600	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
repetitive peak reverse voltage		-	600	V
crest working reverse voltage		-	600	V
reverse voltage	DC	-	600	V
average forward current	square-wave pulse; $\delta = 0.5$ ; $T_{mb} \le 115$ °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	9	Α
repetitive peak forward current	square-wave pulse; $\delta$ = 0.5 ; $t_p$ = 25 $\mu$ s; $T_{mb} \le$ 115 °C	-	18	Α
non-repetitive peak forward current	$t_p$ = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see Figure 3	-	91	Α
	$t_p$ = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	100	Α
storage temperature		-40	150	°C
junction temperature		-	150	°C
	repetitive peak reverse voltage crest working reverse voltage reverse voltage average forward current repetitive peak forward current non-repetitive peak forward current storage temperature	repetitive peak reverse voltage crest working reverse voltage reverse voltage	repetitive peak reverse voltage - crest working reverse voltage - DC - average forward current square-wave pulse; $\delta = 0.5$ ; $T_{mb} \le 115$ °C; - see Figure 1; see Figure 2 repetitive peak forward current square-wave pulse; $\delta = 0.5$ ; $t_p = 25  \mu s$ ; - $T_{mb} \le 115$ °C	repetitive peak reverse voltage - 600 crest working reverse voltage - 600 reverse voltage DC - 600 average forward current square-wave pulse; $\delta = 0.5$ ; $T_{mb} \le 115$ °C; - 9 repetitive peak forward current square-wave pulse; $\delta = 0.5$ ; $t_p = 25  \mu s$ ; - 18 $t_{mb} \le 115$ °C non-repetitive peak forward current $t_p = 10  m s$ ; sine-wave pulse; $t_{j(init)} = 25  ^{\circ}C$ ; - 91 see Figure 3 $t_p = 8.3  m s$ ; sine-wave pulse; $t_{j(init)} = 25  ^{\circ}C$ ; - 100 storage temperature - 40 150

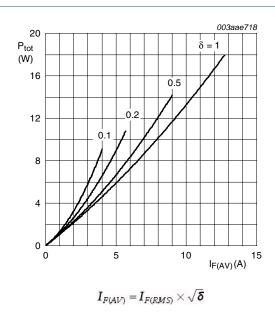
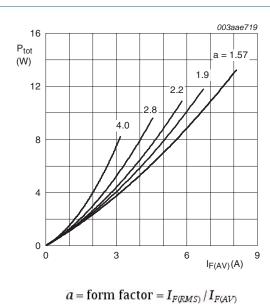


Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



-r(M3) / -r(MV)

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

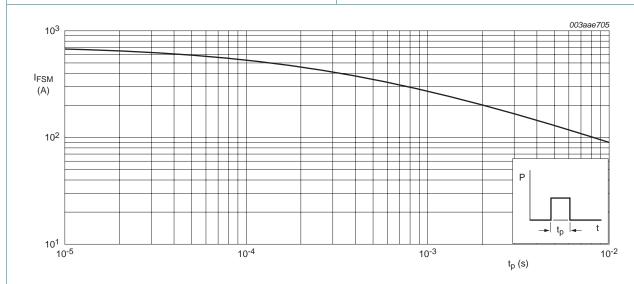


Fig 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	-	2.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	60	-	K/W

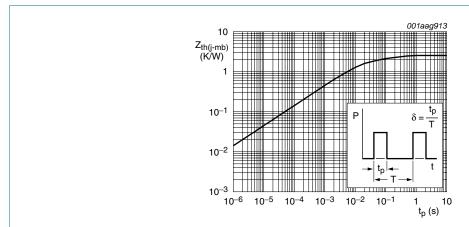
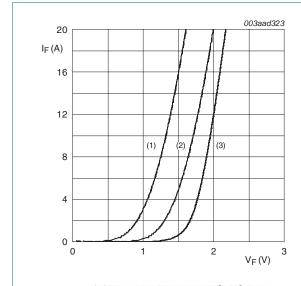


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse width

## 6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static characteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; see <u>Figure 5</u>	-	1.45	1.9	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; see <u>Figure 5</u>	-	1.25	1.7	V
$I_R$	reverse current	$V_R = 600 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	-	1.5	mA
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	50	μA
Dynamic ch	aracteristics					
Q <sub>r</sub>	recovered charge	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; see Figure 6	-	13	-	nC
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; see Figure 6	-	17.5	35	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/µs}$ ; see Figure 6	-	1.5	-	Α
$V_{FR}$	forward recovery voltage	$I_F = 1 \text{ A}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; see Figure 7	-	3.2	-	V



(1)  $T_j = 150 \, ^{\circ}C$ ; typical values (2)  $T_j = 150 \, ^{\circ}C$ ; maximum values

(3)  $T_j = 25$  °C; maximum values

Fig 5. Forward current as a function of forward voltage

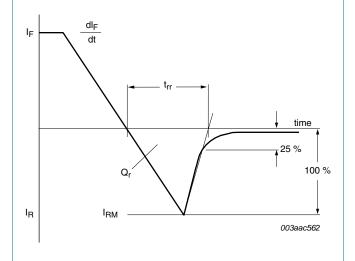
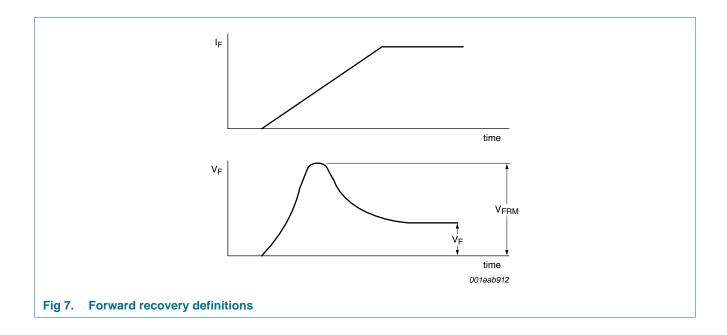


Fig 6. Reverse recovery definitions; ramp recovery



## 7. Package outline

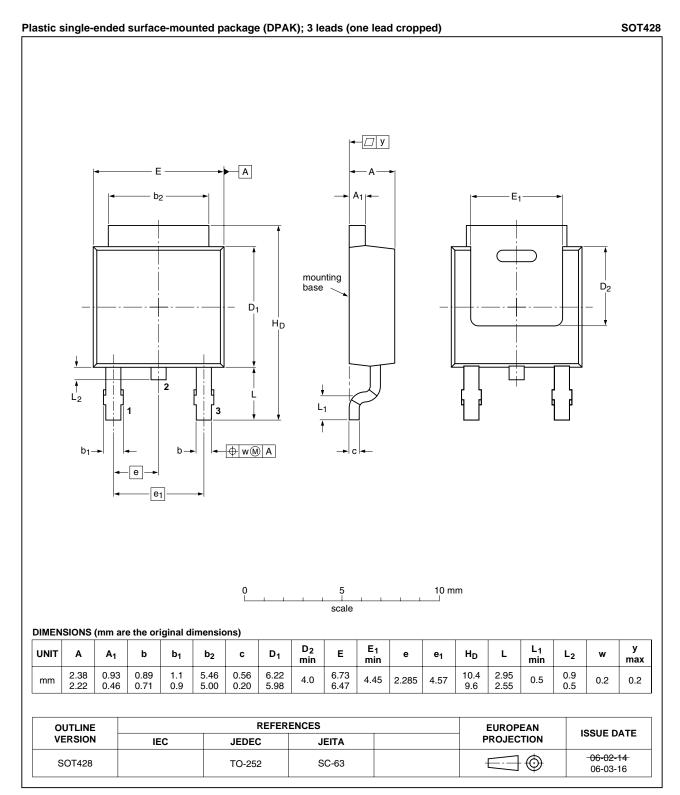
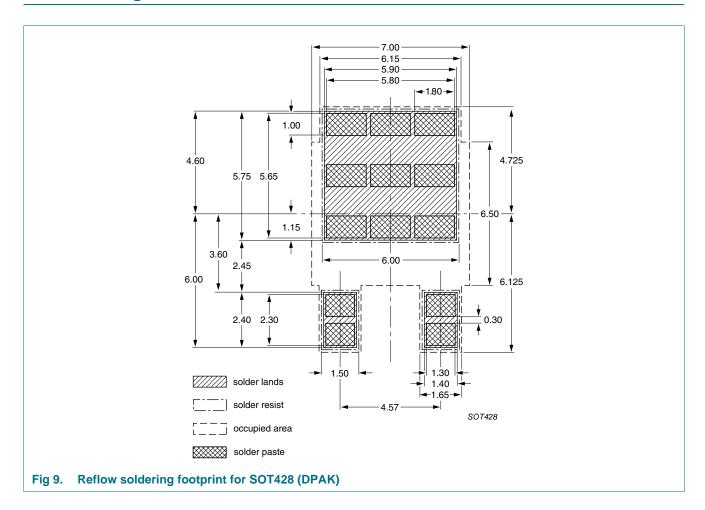


Fig 8. Package outline SOT428 (DPAK)

# 8. Soldering





# 9. Revision history

### Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV29FD-600 v.1	20110307	Product data sheet	-	-

## 10. Legal information

#### 10.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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